



SANYO Semiconductors

DATA SHEET

An ON Semiconductor Company

2SA2013 / 2SC5566 — PNP / NPN Epitaxial Planar Silicon Transistors

DC / DC Converter Applications

Applications

- Relay drivers, lamp drivers, motor drivers, flash.

Features

- Adoption of FBET and MBIT processes.
- High current capacitance.
- Low collector-to-emitter saturation voltage.
- High-speed switching.
- Ultrasmall package facilitates miniaturization in end products.
- High allowable power dissipation.

Specifications () : 2SA2013

Absolute Maximum Ratings at Ta=25°C

Parameter	Symbol	Conditions	Ratings	Unit
Collector-to-Base Voltage	V _{CB0}		(-50)100	V
Collector-to-Emitter Voltage	V _{CES}		(-50)100	V
Collector-to-Emitter Voltage	V _{CEO}		(-)50	V
Emitter-to-Base Voltage	V _{EBO}		(-)6	V
Collector Current	I _C		(-)4	A
Collector Current (Pulse)	I _{CP}		(-)7	A
Base Current	I _B		(-)600	mA
Collector Dissipation	P _C	Mounted on a ceramic board (250mm ² X0.8mm)	1.3	W
		T _c =25°C	3.5	W
Junction Temperature	T _J		150	°C
Storage Temperature	T _{stg}		-55 to +150	°C

Electrical Characteristics at Ta=25°C

Parameter	Symbol	Conditions	Ratings			Unit
			min	typ	max	
Collector Cutoff Current	I _{CBO}	V _{CB} =(-)40V, I _E =0A			(-)1	μA
Emitter Cutoff Current	I _{EBO}	V _{EB} =(-)4V, I _C =0A			(-)1	μA
DC Current Gain	h _{FE}	V _{CE} =(-)2V, I _C =(-)500mA	200		560	
Gain-Bandwidth Product	f _T	V _{CE} =(-)10V, I _C =(-)500mA		(360)400		MHz

Marking : 2SA2013 : AT 2SC5566 : FC

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SANYO Electric Co., Ltd. Semiconductor Company

TOKYO OFFICE Tokyo Bldg., 1-10, 1 Chome, Ueno, Taito-ku, TOKYO, 110-8534 JAPAN

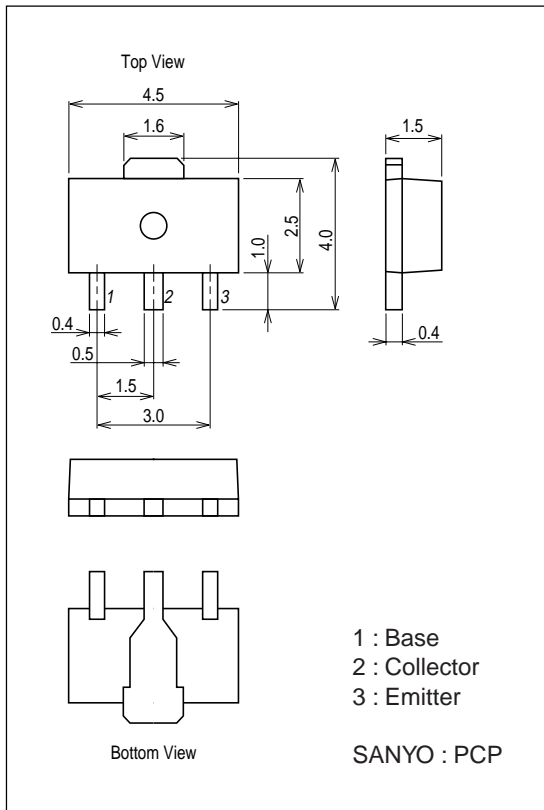
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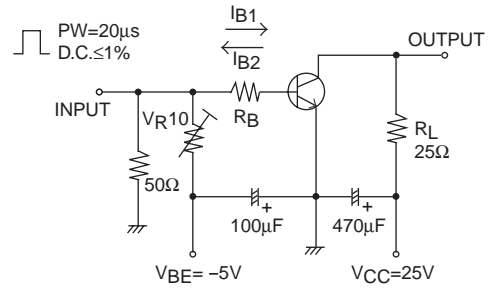
Parameter	Symbol	Conditions	Ratings			Unit
			min	typ	max	
Output Capacitance	Cob	$V_{CB} = (-)10V, f = 1MHz$		(24)15		pF
Collector-to-Emitter Saturation Voltage	$V_{CE(sat)1}$	$I_C = (-)1A, I_B = (-)50mA$		(-105)85	(-180)130	mV
	$V_{CE(sat)2}$	$I_C = (-)2A, I_B = (-)100mA$		(-200)150	(-340)225	mV
Base-to-Emitter Saturation Voltage	$V_{BE(sat)}$	$I_C = (-)2A, I_B = (-)100mA$		(-)0.89	(-)1.2	V
Collector-to-Base Breakdown Voltage	$V_{(BR)CBO}$	$I_C = (-)10\mu A, I_E = 0A$	(-50)100			V
Collector-to-Emitter Breakdown Voltage	$V_{(BR)CES}$	$I_C = (-)100\mu A, R_{BE} = 0\Omega$	(-50)100			V
Collector-to-Emitter Breakdown Voltage	$V_{(BR)CEO}$	$I_C = (-)1mA, R_{BE} = \infty$	(-)50			V
Emitter-to-Base Breakdown Voltage	$V_{(BR)EBO}$	$I_E = (-)10\mu A, I_C = 0A$	(-)6			V
Turn-On Time	t_{on}	See specified Test Circuit.		(30)35		ns
Storage Time	t_{stg}	See specified Test Circuit.		(230)300		ns
Fall Time	t_f	See specified Test Circuit.		(15)20		ns

Package Dimensions

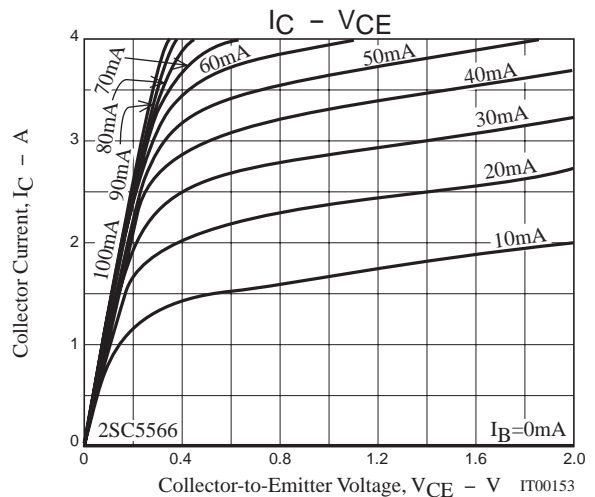
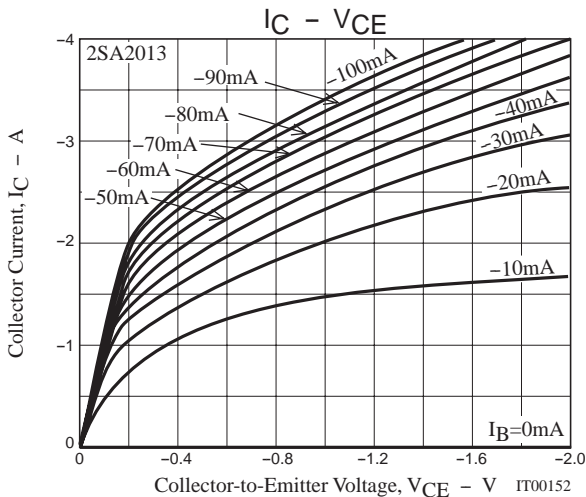
unit : mm
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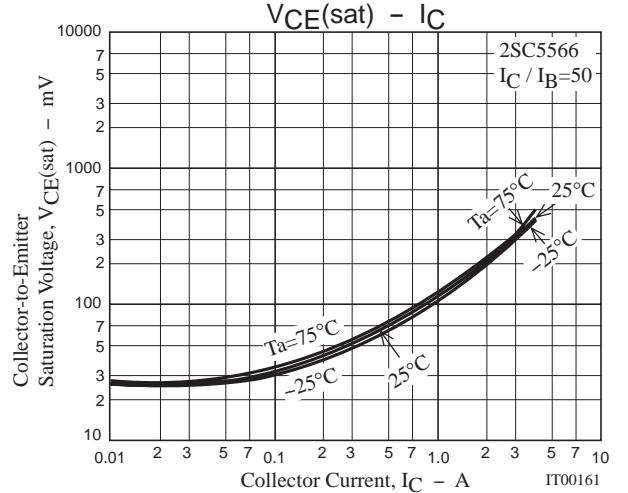
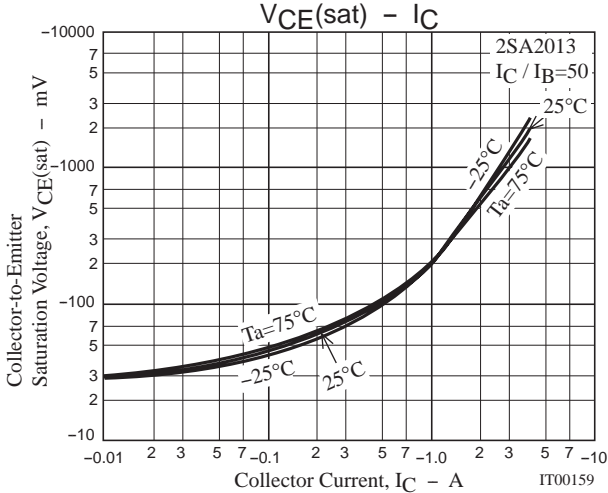
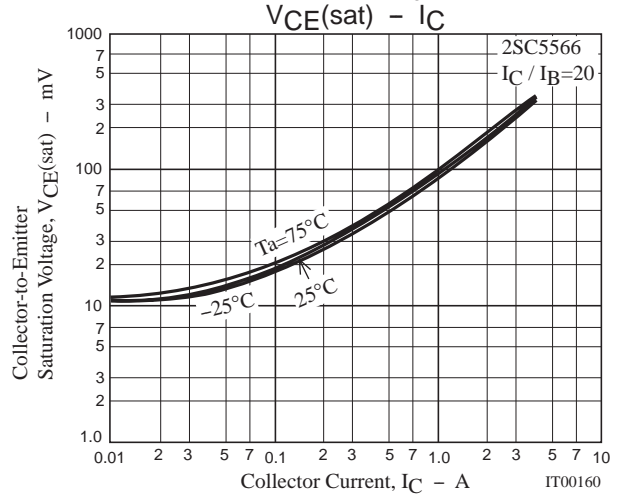
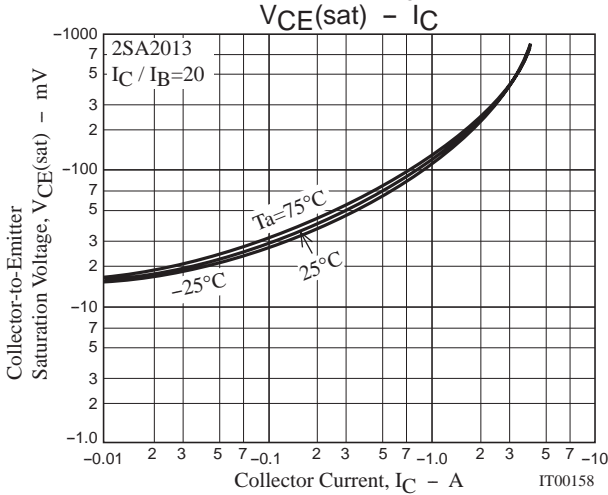
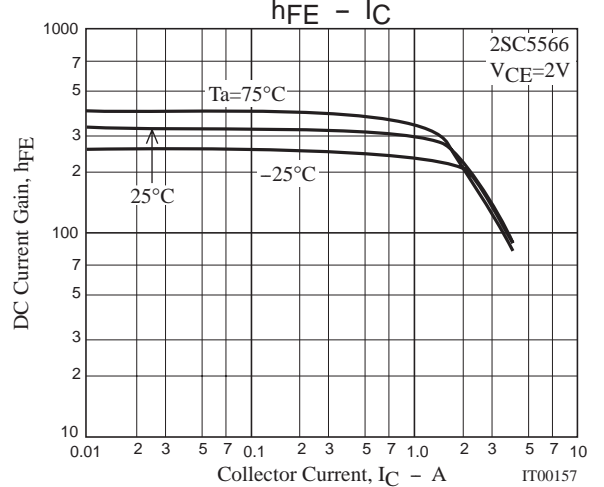
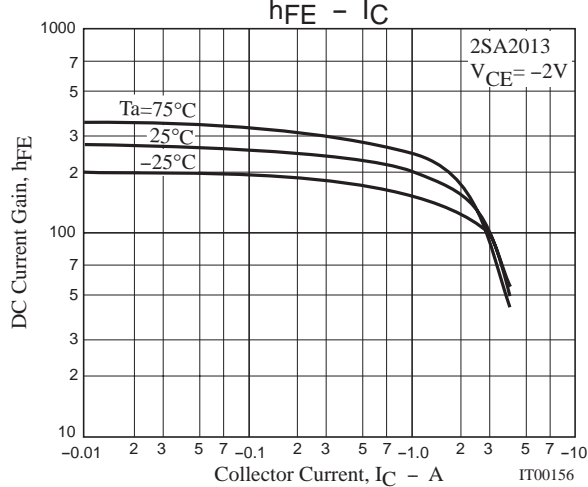
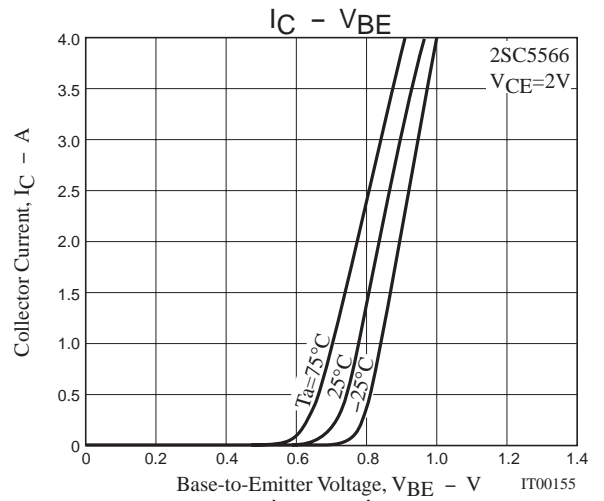
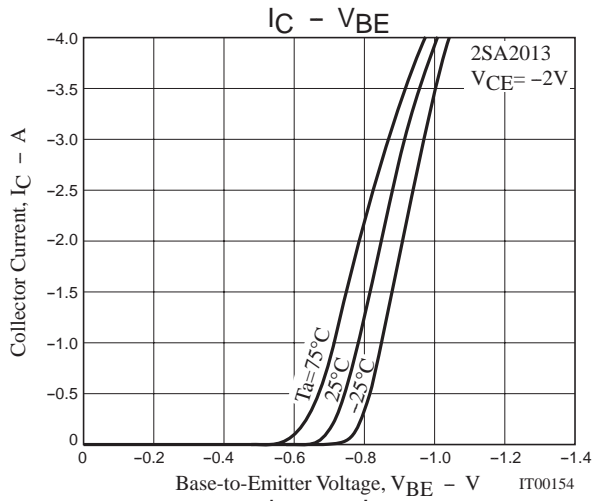


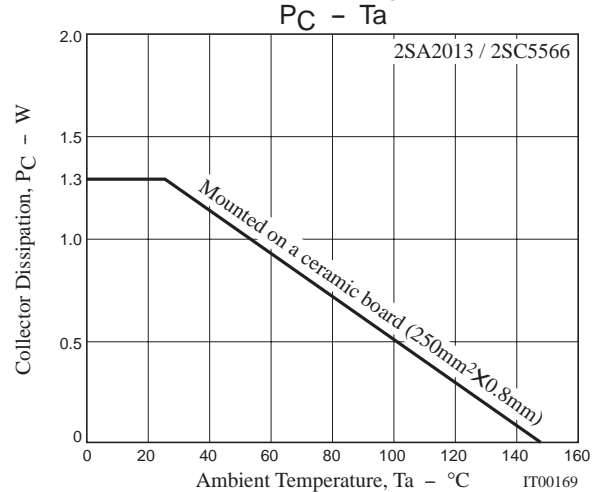
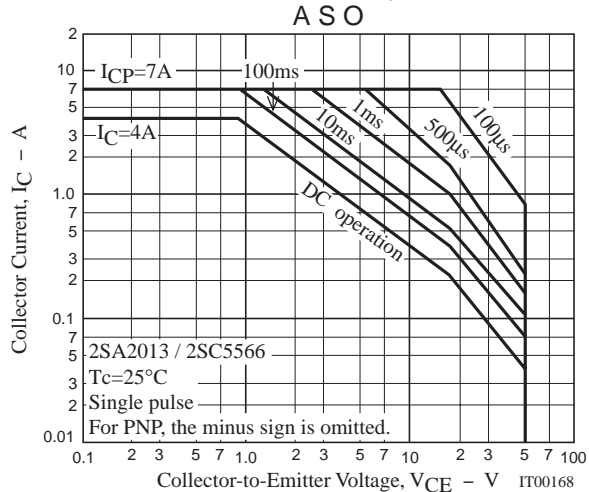
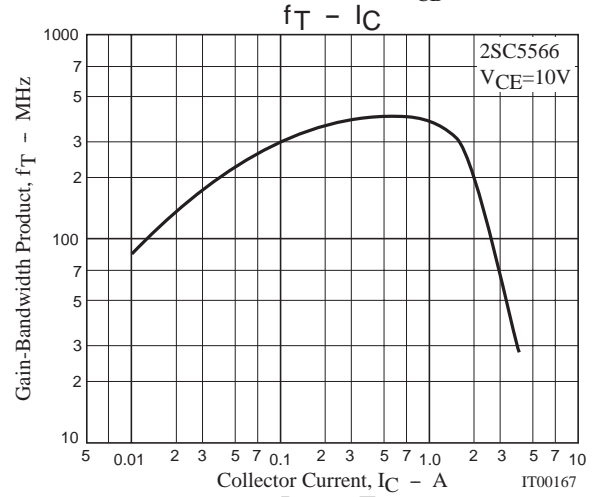
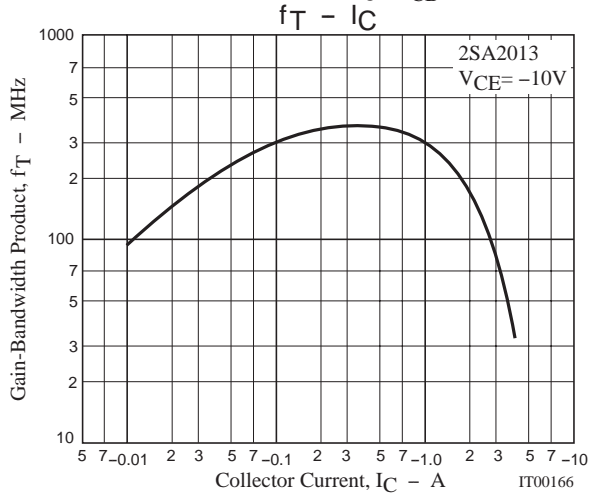
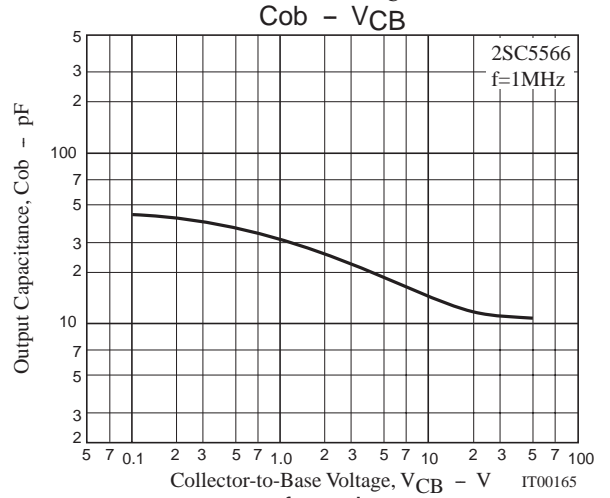
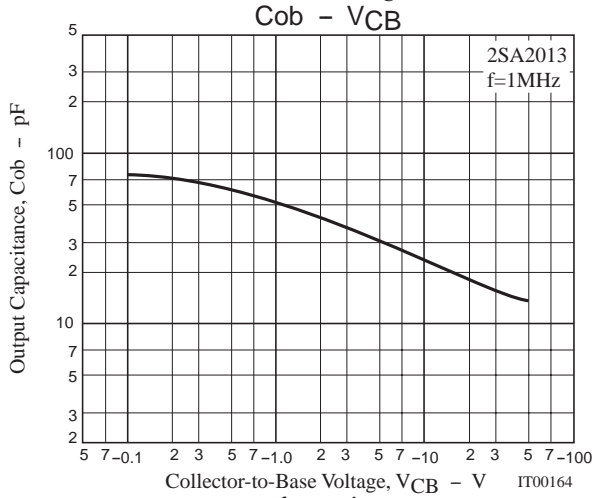
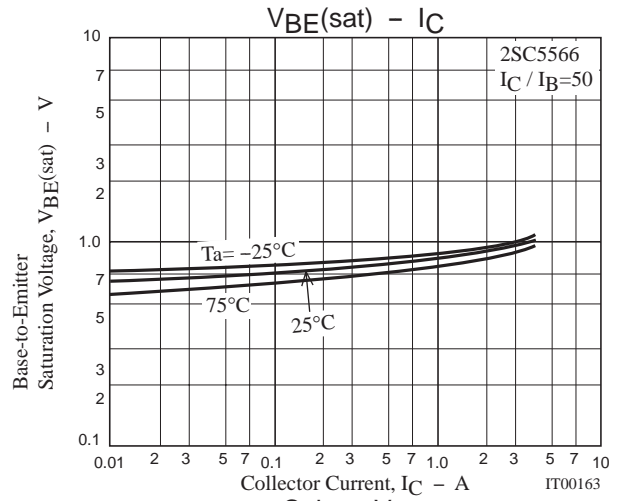
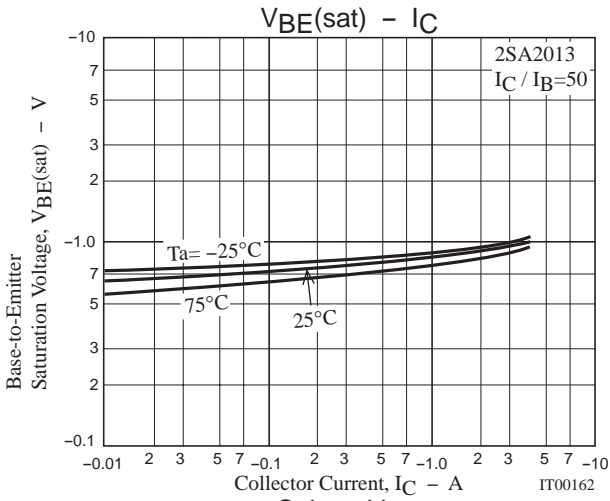
Switching Time Test Circuit

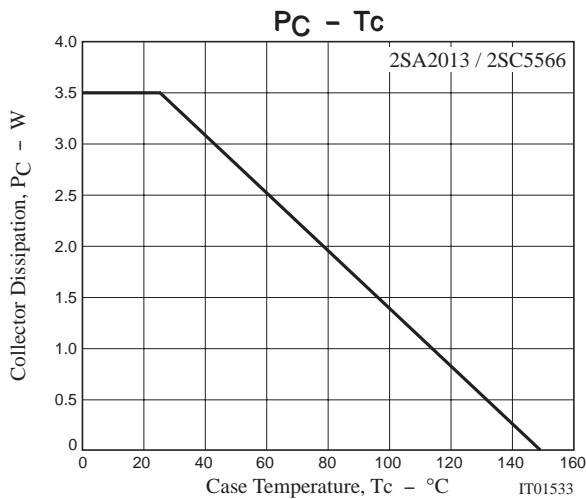


$I_C = 10I_B, I_1 = -10I_2 = 1A$
For PNP, the polarity is reversed.









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